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M. Gröppel, W. Roth, N. Elbel and H. von Seggern, Self-assembly of organopolysilanes on graphite: a scanning tunneling microscopy study 323 (1995) 304

Water

K. Takeuchi, S.S. Perry, M. Salmeron and G.A. Somorjai, The bonding properties of hydrogenated and fluorinated molecules to zirconium oxide thin films: influence of surface defects and water coadsorption 323 (1995) 30

PHYSICAL STATE

Surfaces

Amorphous surfaces

A.M. Ferrari, E. Garrone, G. Spoto, P. Ugliengo and A. Zecchina, Reactions of silica strained rings: an experimental and ab-initio study 323 (1995) 151

H. Tajima, M. Haraguchi and M. Fukui, Surface plasmon polariton radiation from silver films on fluoride films and surface roughness parameters of those silver films 323 (1995) 282

Single crystal surfaces

A. Lessmann, W. Drube and G. Materlik, Backreflection XSW and ARUPS studies of Sb/Ge(001)-2 × 1 323 (1995) 109

I.-S. Hwang, R.E. Martinez, C. Liu and J.A. Golovchenko, High coverage phases of Pb on the Si(111) surface: structures and phase transitions 323 (1995) 241

Low index single crystal surfaces

P.W. Murray, N.G. Condon and G. Thornton, Na adsorption sites on TiO_2(110)-1 × 2 and its 2 × 2 superlattice 323 (1995) L281

T. Suzuki, A. Mikami, K. Uehara and M. Aono, Surface temperature of pulsed-laser-irradiated Si(111)-7 × 7 measured by second-harmonic generation 323 (1995) L293

H. Qi, P.E. Gee, T. Nguyen and R.F. Hicks, Sites for hydrogen adsorption on GaAs(001) 323 (1995) 6

S. Bao, Ph. Hofmann, K.-M. Schindler, V. Fritzsche, A.M. Bradshaw, D.P. Woodruff, C. Casado and M.C. Asensio, The local geometry of reactant and product in a surface reaction: the dehydrogenation of adsorbed ethylene on Ni(111) 323 (1995) 19

K. Takeuchi, S.S. Perry, M. Salmeron and G.A. Somorjai, The bonding properties of hydrogenated and fluorinated molecules to zirconium oxide thin films: influence of surface defects and water coadsorption 323 (1995) 30

H. Kleine, M. Eckhardt, H.J. Jänsch and D. Fick, Adsorption of Li on a Si(100)-2 × 1 surface 323 (1995) 51

D.V. Chakarov and W. Ho, Thermal and photo-induced desorption, dissociation, reactions of H_2O adsorbed on Si(111)7 × 7 323 (1995) 57

M. Breeman, G.T. Barkema and D.O. Boerma, Binding energies and stability of Cu-adatom clusters on Cu(100) and Cu(111) 323 (1995) 71

N. Ikemiya, T. Kubo and S. Hara, In situ AFM observations of oxide film formation on Cu(111) and Cu(100) surfaces under aqueous alkaline solutions 323 (1995) 81

S. Gota, M. Gautier, L. Douillard, N. Thromat, J.P. Duraud and P. Le Fèvre, Influence of the substrate oxidation state in the growth of copper clusters on Al_2O_3(0001) surface: a XANES and EXAFS study 323 (1995) 163

E.S. Hirschorn, D.S. Lin, E.D. Hansen and T.-C. Chiang, Atomic burrowing and hole formation for Au growth on Ag(110) 323 (1995) L299

G. Witte, J.P. Toennies and Ch. Wöll, Comparison of surface phonon dispersion curves for clean and hydrogen covered Rh(111) surfaces 323 (1995) 228

H. Akazawa, Kinetics of Si growth on Ge(100) in Si_2H_6 gas-source molecular beam epitaxy and low-pressure chemical vapor deposition 323 (1995) 269

Surface defects

K. Takeuchi, S.S. Perry, M. Salmeron and G.A. Somorjai, The bonding properties of hydrogenated and fluorinated molecules to zirconium oxide thin films: influence of surface defects and water coadsorption 323 (1995) 30

L.E. Carter and E.A. Carter, F_2 reaction dynamics with defective Si(100): defect-insensitive surface chemistry 323 (1995) 39

Z. Zhou and B. Joós, Vacancy annealing kinetics in finite monolayer patches 323 (1995) 311

Interfaces

Grain boundaries

V.P. Zhdanov and P.R. Norton, Criterion for instability of oxide film growth with respect to formation of cracks 323 (1995) L311

Solid–gas interfaces

A.M. Ferrari, E. Garrone, G. Spoto, P. Ugliengo and A. Zecchina, Reactions of silica strained rings: an experimental and ab-initio study 323 (1995) 151

Non-epitaxial thin film structures

Amorphous thin films

P. Poveda and A. Glachant, Low energy electron-beam-enhanced formation of ultrathin insulating silicon oxynitride layers on Si(100) at moderate temperatures: in situ determination of the band gap energy using electron energy loss spectroscopy 323 (1995) 258

Y. Okuno, A. Shinya, M. Kuwahara, M. Fukui and Y. Shintani, Studies on optical constants of metal films evaporated at low temperatures 323 (1995) 275

Adatoms

P.W. Murray, N.G. Condon and G. Thornton, Na adsorption sites on TiO_2(110)-1 × 2 and its 2 × 2 superlattice 323 (1995) L281

H. Qi, P.E. Gee, T. Nguyen and R.F. Hicks, Sites for hydrogen adsorption on GaAs(001) 323 (1995) 6

M. Breeman, G.T. Barkema and D.O. Boerma, Binding energies and stability of Cu-adatom clusters on Cu(100) and Cu(111) 323 (1995) 71
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G. Witte, J.P. Toennies and Ch. Wöll, Comparison of surface phonon dispersion curves for clean and hydrogen covered Rh(111) surfaces 323 (1995) 228
I.-S. Hwang, R.E. Martinez, C. Liu and J.A. Golovchenko, High coverage phases of Pb on the Si(111) surface: structures and phase transitions 323 (1995) 241
Z. Zhou and B. Joós, Vacancy annealing kinetics in finite monolayer patches 323 (1995) 311

Clusters

M. Breeman, G.T. Barkema and D.O. Boerma, Binding energies and stability of Cu-adatom clusters on Cu(100) and Cu(111) 323 (1995) 71
S. Gota, M. Gautier, L. Douillard, N. Thromat, J.P. Duraud and P. Le Fèvre, Influence of the substrate oxidation state in the growth of copper clusters on Al_2O_3(0001) surface: a XANES and EXAFS study 323 (1995) 163
R.L.C. Wang and H.J. Kreuzer, Clusters embedded in jellium: an effective method for the calculation of surface properties in strong electrostatic fields 323 (1995) 333

Coatings

Z. Zhou and B. Joós, Vacancy annealing kinetics in finite monolayer patches 323 (1995) 311

ELECTRICAL AND MAGNETIC BEHAVIOR

Surfaces and / or films

Insulating films

P. Poveda and A. Glachant, Low energy electron-beam-enhanced formation of ultrathin insulating silicon oxynitride layers on Si(100) at moderate temperatures: in situ determination of the band gap energy using electron energy loss spectroscopy 323 (1995) 258

Insulating surfaces

S. Gota, M. Gautier, L. Douillard, N. Thromat, J.P. Duraud and P. Le Fèvre, Influence of the substrate oxidation state in the growth of copper clusters on Al_2O_3(0001) surface: a XANES and EXAFS study 323 (1995) 163

Metallic films

S. Gota, M. Gautier, L. Douillard, N. Thromat, J.P. Duraud and P. Le Fèvre, Influence of the substrate oxidation state in the growth of copper clusters on Al_2O_3(0001) surface: a XANES and EXAFS study 323 (1995) 163

Semiconducting surfaces

T. Suzuki, A. Mikami, K. Uehara and M. Aono, Surface temperature of pulsed-laser-irradiated Si(111)-7 × 7 measured by second-harmonic generation 323 (1995) L293
H. Akazawa, Kinetics of Si growth on Ge(100) in Si_2H_6 gas-source molecular beam epitaxy and low-pressure chemical vapor deposition 323 (1995) 269

Interfaces

Metal–electrolyte interfaces

X.M. Yang, K. Tonami, L.A. Nagahara, K. Hashimoto, Y. Wei and A. Fujishima, Erratum to "In-situ observation of the electrochemical Hg/Au amalgam process on an Au electrode surface by atomic force microscopy" [Surf. Sci. 319 (1994) L17] 323 (1995) L319

Metal–insulator interfaces

S. Gota, M. Gautier, L. Douillard, N. Thromat, J.P. Duraud and P. Le Fèvre, Influence of the substrate oxidation state in the growth of copper clusters on Al_2O_3(0001) surface: a XANES and EXAFS study 323 (1995) 163
M. Vermeersch, F. Malengreau, R. Sporken and R. Caudano, The aluminium/sapphire interface formation at high temperature: an AES and LEED study 323 (1995) 175
H. Tajima, M. Haraguchi and M. Fukui, Surface plasmon polariton radiation from silver films on fluoride films and surface roughness parameters of those silver films 323 (1995) 282

Semiconductor–insulator interfaces

P. Poveda and A. Glachant, Low energy electron-beam-enhanced formation of ultrathin insulating silicon oxynitride layers on Si(100) at moderate temperatures: in situ determination of the band gap energy using electron energy loss spectroscopy 323 (1995) 258

Instructions for Authors Concerning the Use of Keywords for Indexing in Surface Science

Given below is a listing of keywords for the Subject and Materials Indexes used by Surface Science. The Subject index is divided into three classes: Theoretical Methods, Experimental Methods, and Phenomena. Please indicate below your abstract at least one keyword from as many of the three classes as appropriate to describe the contents of your manuscript. (You may also tick the appropriate box and include this list with your manuscript.) Occasionally it will not be possible to include a keyword from all three classes, e.g., a general theory manuscript will not exhibit a keyword from the Experimental Methods class. In such a case, omit the entry from the inapplicable class. Also, if appropriate, please select a keyword from one of the three classes of the Materials Index, i.e., Elemental and Chemical Identity, Physical State, and Electrical and Magnetic Behavior. You may use multiple keywords in the above mentioned six classes up to a maximum of eight in total. For example, many experimental papers will be characterized by more than one keyword in the Experimental Methods class of the Subject Index as well as by several keywords from the Materials Index.

The keywords will be used as labels for the use in electronic navigation tools. Thus, careful attention to giving a correct, useful description of your work will generate more thorough use of your paper once it is published.

Subject index

Theoretical methods, models and techniques

- ☐ Ab initio quantum chemical methods and calculations
- ☐ Atom–solid interactions, scattering, diffraction
- ☐ Atomistic dynamics
- ☐ Computer simulations
- ☐ Construction and use of effective interatomic interactions
- ☐ Density functional calculations
- ☐ Electron density, excitation spectra calculations
- ☐ Electron–solid interactions, scattering, diffraction
- ☐ Equilibrium thermodynamics and statistical mechanics
- ☐ Green's function methods
- ☐ Ion–solid interactions, scattering, channeling
- ☐ Ising models
- ☐ Jellium models
- ☐ Many body and quasi-particle theories
- ☐ Models of non-equilibrium phenomena
- ☐ Models of non-linear phenomena
- ☐ Models of surface chemical reactions
- ☐ Models of surface kinetics
- ☐ Molecular dynamics
- ☐ Non-equilibrium thermodynamics and statistical mechanics
- ☐ Semi-empirical models and model calculations

Experimental sample preparation and characterization methods

- ☐ Adsorption isotherms
- ☐ Appearance potential spectroscopy
- ☐ Atom–solid reactions
- ☐ Atom–solid scattering and diffraction – elastic
- ☐ Atom–solid scattering and diffraction – inelastic
- ☐ Atomic force microscopy
- ☐ Auger electron spectroscopy
- ☐ Chemical vapor deposition
- ☐ Desorption induced by electronic transitions (DIET)
  - ☐ *Angle resolved DIET* (including electron stimulated desorption ion angular distribution (ESDIAD))
  - ☐ *Electron stimulated desorption (ESD)*
  - ☐ *Photon stimulated desorption (PSD)*
  - ☐ *Surface photochemistry*
- ☐ Electrical transport measurements
- ☐ Electrochemical methods
- ☐ Electron emission measurements
  - ☐ *Exoelectron emission*
  - ☐ *Field emission*
  - ☐ *Photoemission (total yield)*
  - ☐ *Secondary electron emission*
  - ☐ *Thermally-stimulated emission*
- ☐ Electron energy loss spectroscopy
- ☐ Electron microscopy
  - ☐ *Ballistic electron emission microscopy (BEEM)*
  - ☐ *Low-energy electron microscopy (LEEM)*
  - ☐ *Reflection electron microscopy (REM)*
  - ☐ *Scanning electron microscopy (SEM)*
  - ☐ *Scanning transmission electron microscopy (STEM)*
- ☐ Electron–solid diffraction
  - ☐ *Auger electron diffraction*
  - ☐ *Low energy electron diffraction (LEED)*
  - ☐ *Photoelectron diffraction*
  - ☐ *Photoelectron holography*
  - ☐ *Reflection high-energy electron diffraction (RHEED)*
  - ☐ *Transmission high-energy electron diffraction*
- ☐ Electron–solid scattering and transmission – elastic
- ☐ Electron–solid scattering and transmission – inelastic
- ☐ Electron spin resonance
- ☐ Ellipsometry
- ☐ Field emission microscopy
- ☐ Field emission spectroscopy

- ☐ Field ion microscopy
- ☐ Inverse photoemission spectroscopy
- ☐ Ion etching
- ☐ Ion implantation
- ☐ Ion scattering spectroscopy
  - ☐ *High energy ion scattering (HEIS)*
  - ☐ *Low energy ion scattering (LEIS)*
  - ☐ *Medium energy ion scattering (MEIS)*
- ☐ Isotopic exchange/traces
- ☐ Laser methods
  - ☐ *Laser annealing*
  - ☐ *Laser induced thermal desorption (LITD)*
  - ☐ *Resonance enhanced multiphoton ionization mass spectroscopy (REMPI/MS)*
- ☐ Liquid phase epitaxy
- ☐ Magnetic measurements
- ☐ Molecular beam epitaxy
- ☐ Molecule–solid reactions
- ☐ Molecule–solid scattering and diffraction – elastic
- ☐ Molecule–solid scattering and diffraction – inelastic
- ☐ Mössbauer spectroscopy
- ☐ Neutron scattering
- ☐ Non-linear optical methods
  - ☐ *Second harmonic generation*
  - ☐ *Sum frequency generation*
- ☐ Nuclear magnetic resonance
- ☐ Nuclear reaction analysis
- ☐ Photoelectron spectroscopy
  - ☐ *Angle resolved photoemission*
  - ☐ *Soft X-ray photoelectron spectroscopy (using synchrotron radiation)*
  - ☐ *Visible and ultraviolet photoelectron spectroscopy*
  - ☐ *X-ray photoelectron spectroscopy*
- ☐ Photon absorption spectroscopy
  - ☐ *Extended X-ray absorption fine structure (EXAFS)*
  - ☐ *Infrared absorption spectroscopy*
  - ☐ *Near edge extended X-ray absorption fine structure (NEXAFS)*
  - ☐ *Photoacoustic spectroscopy*
  - ☐ *Visible/ultraviolet absorption spectroscopy*
  - ☐ *Surface extended X-ray absorption fine structure (SEXAFS)*
  - ☐ *X-ray absorption spectroscopy*
- ☐ Photon stimulated desorption (non-electronic)
- ☐ Plasma processing
- ☐ Positron spectroscopy
- ☐ Radioactive tracer methods
- ☐ Raman scattering spectroscopy
- ☐ Reflection spectroscopy
- ☐ Scanning tunneling microscopy
- ☐ Scanning tunneling spectroscopies
- ☐ Secondary ion mass spectroscopy
- ☐ Solid phase epitaxy
- ☐ Sputter deposition
- ☐ Surface photovoltage spectroscopy
- ☐ Thermal desorption spectroscopy
- ☐ Work function measurements
- ☐ X-ray emission
- ☐ X-ray scattering, diffraction, and reflection

Phenomena

- ☐ Adhesion
- ☐ Adsorption kinetics
- ☐ Atom emission
- ☐ Atom–solid interactions
- ☐ Auger ejection
- ☐ Catalysis
- ☐ Chemisorption
- ☐ Compound formation
- ☐ Conductivity
- ☐ Corrosion
- ☐ Crystallization
- ☐ Dielectric phenomena
- ☐ Diffusion and migration
- ☐ Electrical transport (conductivity, resistivity, mobility, etc.)
- ☐ Electron bombardment
- ☐ Electron emission
- ☐ Electron–solid interactions
- ☐ Electron stimulated desorption
- ☐ Energy dissipation
- ☐ Epitaxy
- ☐ Etching
- ☐ Evaporation and sublimation
- ☐ Faceting
- ☐ Field effect
- ☐ Field emission
- ☐ Field evaporation
- ☐ Field ionization
- ☐ Friction
- ☐ Growth
- ☐ Hall effect
- ☐ Interface states
- ☐ Ion bombardment
- ☐ Ion emission
- ☐ Ion implantation
- ☐ Ion–solid interactions
- ☐ Light scattering
- ☐ Lubrication
- ☐ Luminescence
  - ☐ *Atom/ion stimulated luminescence*
  - ☐ *Chemiluminescence*
  - ☐ *Electroluminescence*
  - ☐ *Photoluminescence*
- ☐ Magnetic phenomena (cyclotron resonance, phase transitions, etc.)
- ☐ Nucleation
- ☐ Oxidation
- ☐ Photochemistry
- ☐ Photoconductivity
- ☐ Photoelectron diffraction
- ☐ Photoelectron emission
- ☐ Photon emission
- ☐ Photon stimulated desorption
- ☐ Physical adsorption
- ☐ Piezoelectric effect
- ☐ Positron–solid interactions
- ☐ Quantum effects
- ☐ Radiation damage
- ☐ Second harmonic generation
- ☐ Secondary electron emission
- ☐ Self-assembly
- ☐ Sintering
- ☐ Sputtering
- ☐ Sticking
- ☐ Superconductivity
- ☐ Surface chemical reaction
- ☐ Surface diffusion
- ☐ Surface electrical transport (surface conductivity, surface recombination, etc.)
- ☐ Surface electronic phenomena (work function, surface potential, surface states, etc.)
- ☐ Surface energy
- ☐ Surface melting
- ☐ Surface photovoltage
- ☐ Surface relaxation and reconstruction
- ☐ Surface roughening
- ☐ Surface segregation
- ☐ Surface stress
- ☐ Surface structure, morphology, roughness, and topography
- ☐ Surface tension
- ☐ Surface thermodynamics (including phase transitions)
- ☐ Surface waves
  - ☐ *Acoustic waves*
  - ☐ *Capillary waves*
  - ☐ *Magnons*
  - ☐ *Phonons*
  - ☐ *Plasmons*
  - ☐ *Polaritons*
- ☐ Thermal desorption
- ☐ Thermionic emission
- ☐ Tribology
- ☐ Tunneling
- ☐ Vibrations of adsorbed molecules
- ☐ Wetting

Materials index

ELEMENTAL AND CHEMICAL IDENTITY
(Include each component of an interface or multilayer structure as a separate category. Add your own specific elemental or chemical label if a suitable entry is not on the list.)

Elements

- ☐ Alkali metals
- ☐ Alkaline earth metals
- ☐ Aluminum
- ☐ Antimony
- ☐ Arsenic
- ☐ Bismuth
- ☐ Boron
- ☐ Bromine
- ☐ Cadmium
- ☐ Carbon
- ☐ Cerium
- ☐ Chalcogens
- ☐ Chlorine
- ☐ Chromium
- ☐ Cobalt
- ☐ Copper
- ☐ Diamond
- ☐ Gallium
- ☐ Germanium
- ☐ Gold
- ☐ Graphite
- ☐ Hafnium
- ☐ Hydrogen
- ☐ Indium
- ☐ Iodine
- ☐ Iridium
- ☐ Iron
- ☐ Lanthanides
- ☐ Lead
- ☐ Manganese
- ☐ Mercury
- ☐ Molybdenum
- ☐ Nickel
- ☐ Niobium
- ☐ Nitrogen
- ☐ Noble gases
- ☐ Osmium
- ☐ Palladium
- ☐ Phosphorus
- ☐ Platinum
- ☐ Rhenium
- ☐ Rhodium
- ☐ Ruthenium
- ☐ Scandium
- ☐ Silicon
- ☐ Silver
- ☐ Tantalum
- ☐ Technetium
- ☐ Thallium
- ☐ Thorium
- ☐ Tin
- ☐ Titanium
- ☐ Tungsten
- ☐ Uranium
- ☐ Vanadium
- ☐ Ytterbium
- ☐ Yttrium
- ☐ Zinc
- ☐ Zirconium
- ☐ Other .....*

Compounds (non-molecular solids)

- ☐ Alkali halides
- ☐ Alloys
- ☐ Aluminum oxide
- ☐ Barium oxide
- ☐ Biological compounds
- ☐ Borides
- ☐ Boron nitride
- ☐ Cadmium selenide
- ☐ Cadmium sulphide
- ☐ Cadmium telluride
- ☐ Carbides
- ☐ Cobalt oxides
- ☐ Copper oxides
- ☐ Gallium antimonide
- ☐ Gallium arsenide
- ☐ Gallium nitride
- ☐ Gallium phosphide
- ☐ Gallium selenide
- ☐ Halides
- ☐ Hydrides
- ☐ Indium antimonide
- ☐ Indium arsenide
- ☐ Indium oxides
- ☐ Indium phosphide
- ☐ Inorganic compounds
- ☐ Iron oxide
- ☐ Lead telluride
- ☐ Magnesium oxides
- ☐ Mercury telluride
- ☐ Mica
- ☐ Molybdenum oxides
- ☐ Nickel carbide
- ☐ Nickel oxides
- ☐ Nickel sulphide
- ☐ Nitrides
- ☐ Silicides
- ☐ Silicon carbide
- ☐ Silicon–germanium
- ☐ Silicon nitride
- ☐ Silicon oxides
- ☐ Steel
- ☐ Sulphides
- ☐ Tin oxides
- ☐ Tin telluride
- ☐ Titanium carbide
- ☐ Titanium oxide
- ☐ Tungsten oxide
- ☐ Uranium oxide
- ☐ Vanadium oxide
- ☐ Zeolites
- ☐ Zinc oxide
- ☐ Zinc selenide
- ☐ Other .....*

Molecules

- ☐ Alcohols
- ☐ Aldehydes
- ☐ Alkanes
- ☐ Alkenes
- ☐ Alkynes
- ☐ Ammonia
- ☐ Aromatics
- ☐ Biological molecules – nucleic acids
- ☐ Biological molecules – proteins
- ☐ Biological molecules – other .....*
- ☐ Carbon dioxide
- ☐ Carbon monoxide
- ☐ Carboxylic acid
- ☐ Cyanogen
- ☐ Deuterium
- ☐ Esters
- ☐ Ethers
- ☐ Fullerenes
- ☐ Halogens
- ☐ Hydrogen
- ☐ Hydrogen cyanide
- ☐ Hydrogen sulphide
- ☐ Ketones
- ☐ Nitrogen
- ☐ Nitrogen oxides
- ☐ Oxygen
- ☐ Ozone
- ☐ Phosphine
- ☐ Silane
- ☐ Sulphur dioxide
- ☐ Sulphur hexafluoride
- ☐ Water
- ☐ Other .....*

PHYSICAL STATE

Surfaces

- ☐ Amorphous surfaces
- ☐ Dendritic and/or fractile surfaces
- ☐ Glass surfaces
- ☐ Liquid surfaces
- ☐ Polycrystalline surfaces

- ☐ Single crystal surfaces
  - ☐ *Low index single crystal surfaces*
  - ☐ *Stepped single crystal surfaces*
  - ☐ *Vicinal single crystal surfaces*
- ☐ Surface defects
- ☐ Whiskers

Interfaces

- ☐ Crystalline–amorphous interfaces
- ☐ Crystalline–glass interfaces
- ☐ Grain boundaries
- ☐ Liquid–gas interfaces
- ☐ Single crystal epitaxy
- ☐ Solid–liquid interfaces
- ☐ Solid–gas interfaces

Heterostructures

- ☐ Heterojunctions
- ☐ Quantum wells
- ☐ Superlattices

Non-epitaxial thin film structures

- ☐ Amorphous thin films
- ☐ Ceramic thin films
- ☐ Glassy thin films
- ☐ Polycrystalline thin films

☐ **Adatoms**

☐ **Clusters**

Particulate composites

- ☐ Blacks
- ☐ Ceramics
- ☐ Powders

☐ **Coatings**

☐ **Porous solids**

ELECTRICAL AND MAGNETIC BEHAVIOR

Surfaces and/or films

- ☐ Insulating films
- ☐ Insulating surfaces
- ☐ Magnetic films
- ☐ Magnetic surfaces
- ☐ Metallic films
- ☐ Metallic surfaces
- ☐ Semiconducting films
- ☐ Semiconducting surfaces
- ☐ Superconducting films
- ☐ Superconducting surfaces

Interfaces

- ☐ Magnetic interfaces
- ☐ Metal–electrolyte interfaces
- ☐ Metal–insulator interfaces
- ☐ Metal–metal interfaces
- ☐ Metal–semiconductor interfaces
- ☐ Schottky barrier
- ☐ Semiconductor–electrolyte interfaces
- ☐ Semiconductor–insulator interfaces
- ☐ Semiconductor–semiconductor interfaces
- ☐ Semiconductor–superconductor interfaces
- ☐ Other interfaces .....*

Heterostructures and thin film structures

- ☐ Metal–metal magnetic heterostructures
- ☐ Metal–metal magnetic thin film structures
- ☐ Metal–metal nonmagnetic heterostructures
- ☐ Metal–metal nonmagnetic thin film structures
- ☐ Metal–oxide–semiconductor (MOS) structures
- ☐ Metal–semiconductor magnetic heterostructures
- ☐ Metal–semiconductor magnetic thin film structures
- ☐ Metal–semiconductor nonmagnetic heterostructures
- ☐ Metal–semiconductor nonmagnetic thin film structures
- ☐ Semiconductor–semiconductor heterostructures
- ☐ Semiconductor–semiconductor thin film structures
- ☐ Superconductor–semiconductor heterostructures
- ☐ Superconductor–semiconductor thin film structures
- ☐ Other heterostructures .....*
- ☐ Other thin film structures .....*

☐ **Contacts**

*Please, fill in necessary new Materials Index Keyword. If the new keyword is indicated on the manuscript, please, make clear to which subcategory it belongs.